

BV <sub>CES</sub>	400±30V
ا <sub>C</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.6V
E <sub>AS</sub>	300mJ

#### Features

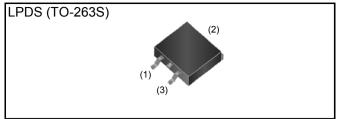
- 1) Low Collector Emitter Saturation Voltage
- 2) High Self-Clamped Inductive Switching Energy
- 3) Built in Gate-Emitter Protection Diode
- 4) Built in Gate-Emitter Resistance
- 5) Qualified to AEC-Q101
- 6) Pb free Lead Plating ; RoHS Compliant

#### Applications

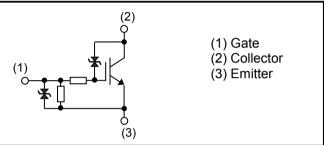
Ignition Coil Driver Circuits

Solenoid Driver Circuits

#### Outline



#### Inner Circuit



#### Packaging Specifications

	Packaging	Taping
	Reel Size (mm)	330
Tuno	Tape Width (mm)	24
Туре	Basic Ordering Unit (pcs)	1,000
	Packing Code	TL
	Marking	RGPR30NS40

#### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Collector - Emitter Voltage	V <sub>CES</sub>	430	V	
Emitter-Collector Voltage (V <sub>GE</sub> = 0)	V <sub>EC</sub>	25	V	
Gate - Emitter Voltage	V <sub>GES</sub>	±10	V	
Collector Current	۱ <sub>C</sub>	30	А	
Avalancha Energy (Single Dulae)	$T_j = 25^{\circ}C$	E <sub>AS</sub>	300	mJ
Avalanche Energy (Single Pulse)	T <sub>j</sub> = 150°C	E <sub>AS</sub> *2	180	mJ
Power Dissipation	P <sub>D</sub>	125	W	
Operating Junction Temperature	Tj	-40 to +175	°C	
Storage Temperature	T <sub>stg</sub>	–55 to +175	°C	

#### •Thermal Resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Onit
Thermal Resistance IGBT Junction - Case	R <sub>θ(j-c)</sub>	-	-	1.20	°C/W

## •Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

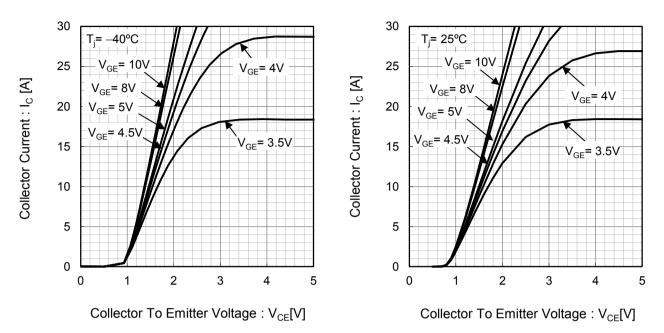
Deremeter	Symbol	Conditions	Values			L lus it	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
		I <sub>C</sub> = 2mA, V <sub>GE</sub> = 0V					
Collector - Emitter Breakdown Voltage	$BV_{CES}$	T <sub>j</sub> = 25°C	370	400	430	V	
		$T_j = -40$ to $175^{\circ}C^{*2}$	365	-	435	V	
Emitter - Collector Breakdown Voltage	BV <sub>EC</sub>	I <sub>C</sub> = –10mA, V <sub>GE</sub> = 0V	25	35	-	V	
Gate - Emitter Breakdown Voltage		$I_G = \pm 5 mA$ , $V_{CE} = 0V$	±12	-	±17	V	
		V <sub>CE</sub> = 250V, V <sub>GE</sub> = 0V					
Collector Cut - off Current	I <sub>CES</sub>	$T_j = 25^{\circ}C$	-	-	7	μA	
		$T_{j} = 150^{\circ}C^{*2}$	-	-	100	μA	
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE}$ = ±10V, $V_{CE}$ = 0V	±0.4	±0.6	±1.2	mA	
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 12mA					
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	T <sub>j</sub> = 25°C	1.3	1.7	2.1	V	
		$T_{j} = 150^{\circ}C^{*2}$	-	1.3	-	V	
		I <sub>C</sub> = 12A, V <sub>GE</sub> = 5V					
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T <sub>j</sub> = 25°C	-	1.60	2.00	V	
		T <sub>j</sub> = 150°C	-	1.80	-	V	
		I <sub>C</sub> = 5A, V <sub>GE</sub> = 4.5V					
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	T <sub>j</sub> = 25°C	-	1.17	1.50	V	
-		T <sub>j</sub> = 150°C	-	1.19	-	V	

### •Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Devenuetor	Cumhal	Conditions	Values			L Locit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
		I <sub>C</sub> = 12A, V <sub>GE</sub> = 4V					
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	T <sub>j</sub> = 25°C	-	1.70	2.10	V	
5		T <sub>j</sub> = 150°C	-	1.90	-	V	
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 10V	-	1330	-		
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	220	-	pF	
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	71	-		
Total Gate Charge	Qg	V <sub>CE</sub> = 12V, I <sub>C</sub> = 10A, V <sub>GE</sub> = 5V	-	22	-	nC	
Turn - on Delay Time <sup>*1,*2</sup>	t <sub>d(on)</sub>		0.11	0.19	0.50		
Rise Time <sup>*1,*2</sup>	t <sub>r</sub>	$I_{\rm C} = 8A, V_{\rm CC} = 300V,$	0.10	0.18	0.50	μs	
Turn - off Delay Time <sup>*1,*2</sup>	t <sub>d(off)</sub>	V <sub>GE</sub> = 5V, R <sub>G</sub> = 100Ω, L=5mH, T <sub>j</sub> =25°C	0.9	1.4	4.0		
Fall Time <sup>*1,*2</sup>	t <sub>f</sub>	f		1.8	5.5		
Turn - on Delay Time <sup>*1</sup>	t <sub>d(on)</sub>		-	0.18	-	μs	
Rise Time <sup>*1</sup>	t <sub>r</sub>	I <sub>C</sub> = 8A, V <sub>CC</sub> = 300V, V <sub>GE</sub> = 5V, R <sub>G</sub> = 100Ω,	-	0.21	-		
Turn - off Delay Time <sup>*1</sup>	t <sub>d(off)</sub>	L=5mH, $T_j$ =150°C	-	1.7	-		
Fall Time <sup>*1</sup>	t <sub>f</sub>		-	3.0	-		
	E <sub>AS</sub>	L = 5mH, V <sub>GE</sub> = 5V, V <sub>CC</sub> = 30V, R <sub>G</sub> = 1kΩ,					
Avalanche Energy (Single Pulse)		T <sub>j</sub> = 25°C	300	-	-	mJ	
		$T_{j} = 150^{\circ}C^{*2}$	180	-	-	mJ	
Gate Series Resistance	R <sub>G</sub>		70	100	130	Ω	
Gate - Emitter Resistance	$R_{GE}$		8	16	24	kΩ	

\*1) Assurance items according to our measurement definition (Fig.18)

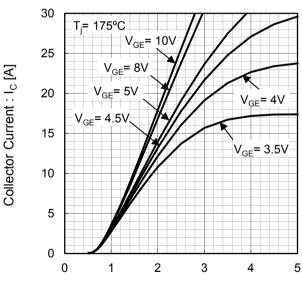
\*2) Design assurance items



#### Fig.1 Typical Output Characteristics

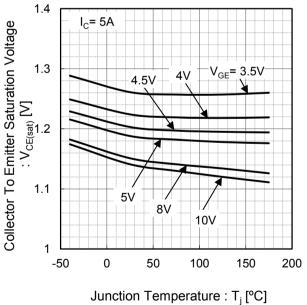
Fig.2 Typical Output Characteristics

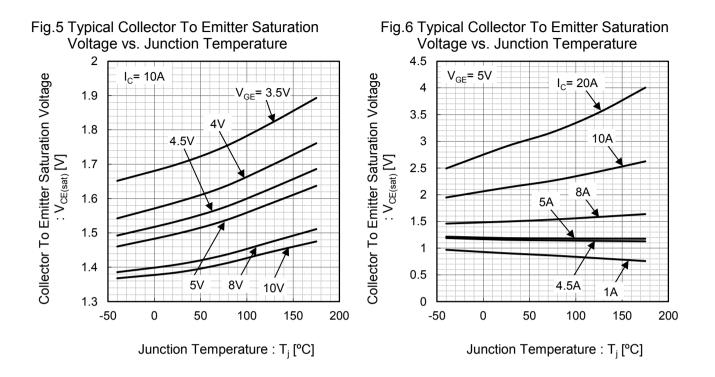
#### Fig.3 Typical Output Characteristics



Collector To Emitter Voltage :  $V_{CE}[V]$ 

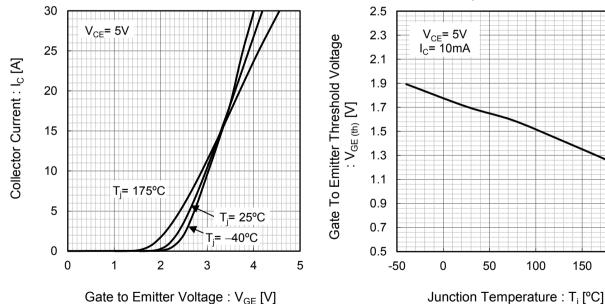
Fig.4 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature





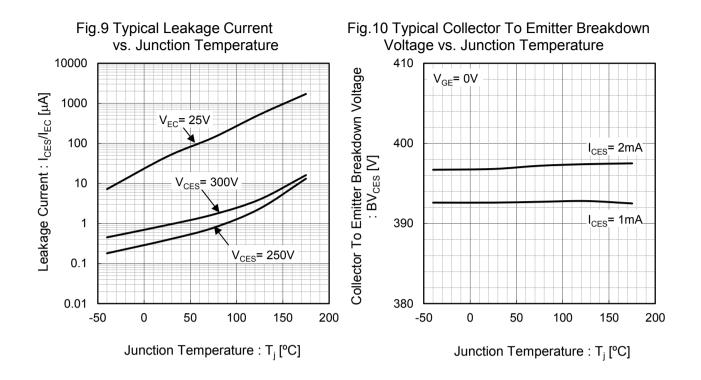
#### Fig.7 Typical Transfer Characteristics

Fig.8 Typical Gate To Emitter Threshold Voltage vs. Junction Temperature



150

200



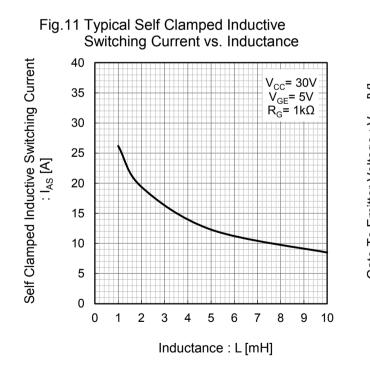
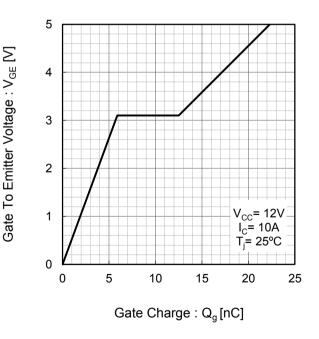
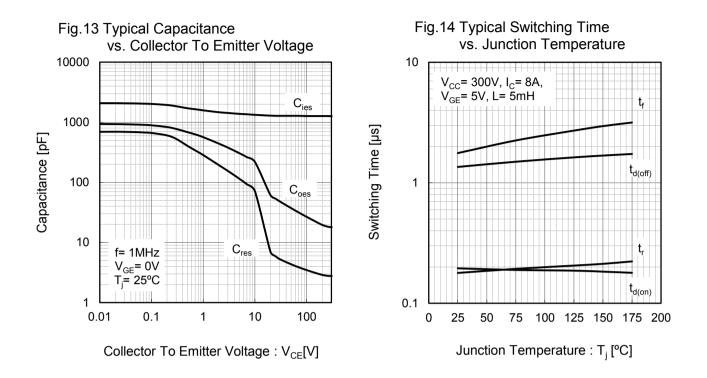
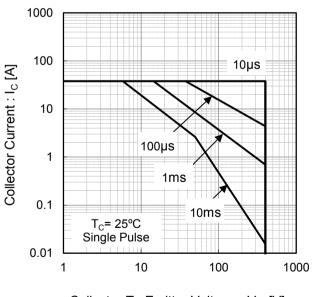


Fig.12 Typical Gate Charge





#### Fig.15 Forward Bias Safe Operating Area



Collector To Emitter	Voltage :	V <sub>CE</sub> [V]
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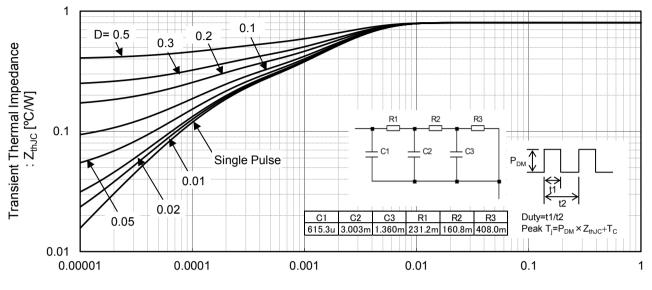


Fig.16 Transient Thermal Impedance

Pulse Width : t1[s]

#### Inductive Load Switching Circuit and Waveform

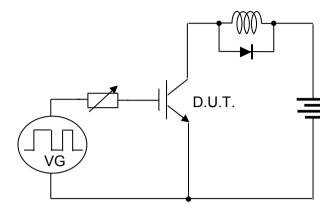


Fig.17 Inductive Load Switching Circuit

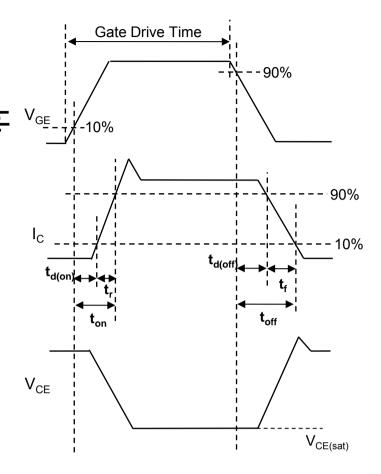


Fig.18 Inductive Load Switching Waveform

#### •Self Clamped Inductive Switching Circuit and Waveform

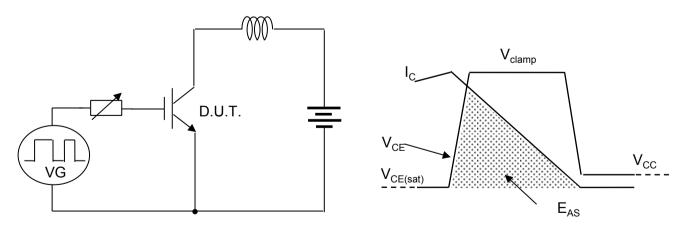


Fig.19 Self Clamped Inductive Switching Ciruit

Fig.20 Self Clamped Inductive Switching Waveform

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Part Number	RGPR30NS40HR
Package	LPDS
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes